NSN 5962-01-436-3504

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Features Provided:
Burn in, mil-std-883, class b and w/clock and programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Pin grid array
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Product Name:
Programmable digital gate array
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Time Rating Per Chacteristic:
10.00 nanoseconds output
Memory Device Type:
Ram
Precious Material And Location:
Terminal leads gold
Terminal Type And Quantity:
156 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A458a0